

**METALLIZED POLYESTER FILM CAPACITOR  
D.C MULTIPURPOSE APPLICATIONS**

**Typical applications:** this series combines small size, good performances in by-passing, blocking and interference suppression in low voltage applications (i.e.: AUTOMOTIVE).

PRODUCT CODE: **R66**

**p = 7.5mm**

**Note:** R66 series has replaced the R84 series (available only upon request).

For new design we suggest the use of the R66 series

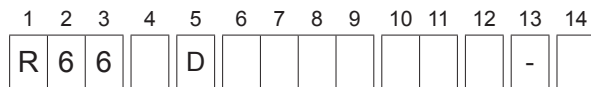
B	<3.5	≥4.0
Ød ±0.05	0.5	0.6

All dimensions are in mm.

Pitch (mm)	Box thickness (B) (mm)	Maximum dimensions (mm)		
		B max	H max	L max
7.5	All	B +0.1	H +0.1	L +0.2

**PRODUCT CODE SYSTEM**

The part number, comprising 14 digits, is formed as follows:



- Digit 1 to 3 Series code.
- Digit 4 d.c. rated voltage:  
C = 50V D = 63V E = 100V  
I = 250V M = 400V P = 630V
- Digit 5 Pitch: D = 7.5 mm
- Digit 6 to 9 Digits 7 - 8 - 9 indicate the first three digits of Capacitance value and the 6th digit indicates the number of zeros that must be added to obtain the Rated Capacitance in pF.
- Digit 10 to 11 Mechanical version and/or packaging (table 1)
- Digit 12 Identifies the dimensions and electrical characteristics.
- Digit 13 Internal use
- Digit 14 Capacitance tolerance:  
J=5%; K=10%; M=20%.

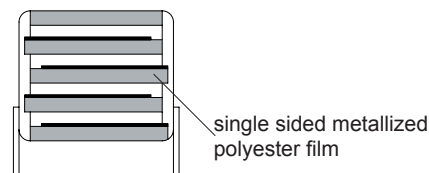
Table 1 (for more detailed information, please refer to page 14).

Standard packaging style	Lead length (mm)	Taping style Figure No.	Ordering code (Digit 10 to 11)
AMMO-PACK		1	DQ
AMMO-PACK		2	28
Reel Ø 355 mm		1	CK
Loose, short leads	4 <sup>+2</sup>		AA
Loose, long leads	17 <sup>+1/-2</sup>		Z3

**GENERAL TECHNICAL DATA**

- Dielectric:** polyester film (polyethylene terephthalate).
- Plates:** aluminium layer deposited by evaporation under vacuum.
- Winding:** non-inductive type.
- Leads:** tinned wire.
- Protection:** plastic case, thermosetting resin filled.  
Box material is solvent resistant and flame retardant according to UL94.
- Marking:** Capacitance, tolerance, D.C. rated voltage.
- Climatic category:** 55/105/56 IEC 60068-1
- Operating temperature range:** -55 to +105°C  
For stacked technology an upper operating temperature of +125°C is allowed for a max operating time of 1000 h.
- Related documents:** IEC 60384-2

**Winding scheme**



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**STACKED VERSION**

Rated Cap.	50Vdc/30Vac Std dimensions				Max dv/dt (V/μs)	Max K <sub>0</sub> (V <sup>2</sup> /μs)	Part Number
	B	H	L	p			
0.68 μF	3.0	8.0	10.0	7.5	100	10 E3	R66CD3680--6--
1.0 μF	3.0	8.0	10.0	7.5	100	10 E3	R66CD4100--6--
1.5 μF	4.0	9.0	10.0	7.5	100	10 E3	R66CD4150--6--
2.2 μF	5.0	10.5	10.0	7.5	100	10 E3	R66CD4220--6--
3.3 μF	5.0	10.5	10.0	7.5	100	10 E3	R66CD4330--6--
4.7 μF	6.0	12.0	10.5	7.5	100	10 E3	R66CD4470--6--

Mechanical version and packaging (Table1) \_\_\_\_\_  
Internal use \_\_\_\_\_  
Tolerance: J (±5%); K (±10%); M (±20%) \_\_\_\_\_

Rated Cap.	100Vdc/63Vac Std dimensions				Max dv/dt (V/μs)	Max K <sub>0</sub> (V <sup>2</sup> /μs)	Part Number
	B	H	L	p			
0.068μF	3.0	8.0	10.0	7.5	150	30 E3	R66ED2680--7--
0.10 μF	3.0	8.0	10.0	7.5	150	30 E3	R66ED3100--7--
0.15 μF	3.0	8.0	10.0	7.5	150	30 E3	R66ED3150--7--
0.22 μF	3.0	8.0	10.0	7.5	150	30 E3	R66ED3220--7--
0.33 μF	4.0	9.0	10.0	7.5	150	30 E3	R66ED3330--7--
0.47 μF	4.0	9.0	10.0	7.5	150	30 E3	R66ED3470--7--
0.68 μF	4.0	9.0	10.0	7.5	150	30 E3	R66ED3680--7--
1.0 μF	5.0	10.5	10.0	7.5	150	30 E3	R66ED4100--7--
1.5 μF	6.0	12.0	10.5	7.5	150	30 E3	R66ED4150--6--

Mechanical version and packaging (Table1) \_\_\_\_\_  
Internal use \_\_\_\_\_  
Tolerance: J (±5%); K (±10%); M (±20%) \_\_\_\_\_

Rated Cap.	63Vdc/40Vac Std dimensions				Max dv/dt (V/μs)	Max K <sub>0</sub> (V <sup>2</sup> /μs)	Part Number
	B	H	L	p			
0.33 μF	3.0	8.0	10.0	7.5	120	15 E3	R66DD3330--7--
0.47 μF	3.0	8.0	10.0	7.5	120	15 E3	R66DD3470--6--
0.68 μF	4.0	9.0	10.0	7.5	120	15 E3	R66DD3680--7--
1.0 μF	4.0	9.0	10.0	7.5	120	15 E3	R66DD4100--7--
1.5 μF	5.0	10.5	10.0	7.5	120	15 E3	R66DD4150--7--
2.2 μF	6.0	12.0	10.5	7.5	120	15 E3	R66DD4220--6--
3.3 μF	6.0	12.0	10.5	7.5	120	15 E3	R66DD4330--6--

Mechanical version and packaging (Table1) \_\_\_\_\_  
Internal use \_\_\_\_\_  
Tolerance: J (±5%); K (±10%); M (±20%) \_\_\_\_\_

Rated Cap.	250Vdc/160Vac Std dimensions				Max dv/dt (V/μs)	Max K <sub>0</sub> (V <sup>2</sup> /μs)	Part Number
	B	H	L	p			
0.022μF	3.0	8.0	10.0	7.5	200	100 E3	R66ID 2220--7--
0.033μF	3.0	8.0	10.0	7.5	200	100 E3	R66ID 2330--7--
0.047μF	3.0	8.0	10.0	7.5	200	100 E3	R66ID 2470--7--
0.068μF	3.0	8.0	10.0	7.5	200	100 E3	R66ID 2680--6--
0.10 μF	4.0	9.0	10.0	7.5	200	100 E3	R66ID 3100--7--
0.15 μF	4.0	9.0	10.0	7.5	200	100 E3	R66ID 3150--7--
0.22 μF	5.0	10.5	10.0	7.5	200	100 E3	R66ID 3220--7--
0.33 μF	6.0	12.0	10.5	7.5	200	100 E3	R66ID 3330--6--

Mechanical version and packaging (Table1) \_\_\_\_\_  
Internal use \_\_\_\_\_  
Tolerance: J (±5%); K (±10%); M (±20%) \_\_\_\_\_

**a) WOUND version**

**b) STACKED version**

Rated Cap.	400Vdc/200Vac Std dimensions				Max dv/dt (V/μs)	Max K <sub>0</sub> (V <sup>2</sup> /μs)	Part Number
	B	H	L	p			
6800 pF	3.0	8.0	10.0	7.5	275	220 E3	R66MD1680--7--
0.010μF	3.0	8.0	10.0	7.5	275	220 E3	R66MD2100--7--
0.015μF	3.0	8.0	10.0	7.5	275	220 E3	R66MD2150--7--
0.022μF	3.0	8.0	10.0	7.5	275	220 E3	R66MD2220--6--
0.033μF	4.0	9.0	10.0	7.5	275	220 E3	R66MD2330--7--
0.047μF	4.0	9.0	10.0	7.5	275	220 E3	R66MD2470--7--
0.068μF	5.0	10.5	10.0	7.5	275	220 E3	R66MD2680--7--
0.10 μF	6.0	12.0	10.5	7.5	275	220 E3	R66MD3100--6--
0.15 μF	6.0	12.0	10.5	7.5	275	220 E3	R66MD3150--6--

Mechanical version and packaging (Table1) \_\_\_\_\_  
Internal use \_\_\_\_\_  
Tolerance: J (±5%); K (±10%); M (±20%) \_\_\_\_\_

Rated Cap.	630Vdc/220Vac* Std dimensions				Max dv/dt (V/μs)	Max K <sub>0</sub> (V <sup>2</sup> /μs)	Part Number
	B	H	L	p			
a) 1000 pF	3.0	8.0	10.0	7.5	40	50 E3	R66PD 1100--1--
a) 1500 pF	3.0	8.0	10.0	7.5	40	50 E3	R66PD1150--1--
a) 2200 pF	3.0	8.0	10.0	7.5	40	50 E3	R66PD 1220--1--
a) 3300 pF	3.0	8.0	10.0	7.5	40	50 E3	R66PD 1330--1--
a) 4700 pF	3.0	8.0	10.0	7.5	40	50 E3	R66PD 1470--1--
a) 6800 pF	4.0	9.0	10.0	7.5	40	50 E3	R66PD 1680--1--
b) 0.010μF	4.0	9.0	10.0	7.5	300	378 E3	R66PD 2100--7--
b) 0.015μF	4.0	9.0	10.0	7.5	300	378 E3	R66PD 2150--7--
b) 0.022μF	5.0	10.5	10.0	7.5	300	378 E3	R66PD 2220--7--
b) 0.033μF	6.0	12.0	10.5	7.5	300	378 E3	R66PD 2330--6--
b) 0.047μF	6.0	12.0	10.5	7.5	300	378 E3	R66PD 2470--6--

Mechanical version and packaging (Table1) \_\_\_\_\_  
Internal use \_\_\_\_\_  
Tolerance: J (±5%); K (±10%); M (±20%) \_\_\_\_\_

All dimensions are in mm.

Note: If the working voltage (V) is lower than the rated voltage (V<sub>R</sub>), the capacitor may work at higher dv/dt. In this case the maximum value allowed is obtained multiplying the above value (see table dv/dt) with the ratio V<sub>R</sub>/V.

The pulse characteristic K<sub>0</sub> depends on the voltage wave-form and in any case it cannot overcome the value given in the above table.

\*Not suitable for across-the-line applications. Please refer to Interference Suppression Capacitors (page 151).

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$p = 7.5 \text{ mm}$   
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**ELECTRICAL CHARACTERISTICS**

**Rated voltage ( $V_R$ ):**

50 Vdc 63 Vdc 100 Vdc  
250 Vdc 400 Vdc 630 Vdc

**Rated temperature ( $T_R$ ):** +85 °C

**Temperature derated voltage:**

for temperatures between +85°C and the upper operating temperature (+105°C for wound technology and +125°C for stacked technology) a decreasing factor of 1.25% per degree °C on the rated voltage  $V_R$  (d.c. and a.c.) has to be applied.

**Capacitance range:** 1000 pF to 4.7  $\mu\text{F}$

**Capacitance values:**

E6 series (IEC 60063 Norm).

**Capacitance tolerances** (measured at 1 kHz):

$\pm 5\%$  (J);  $\pm 10\%$  (K);  $\pm 20\%$  (M).

**Total self-inductance (L):**  $\approx 8\text{nH}$

(lead length  $\sim 2\text{mm}$ )

**Dissipation factor (DF):**

$\text{tg}\delta 10^{-4}$  at +25°C  $\sim 5^\circ\text{C}$

kHz	$\text{tg}\delta \times 10^{-4}$
1	$\leq 100$
10	$\leq 150$

**Insulation resistance:**

**Test conditions**

Temperature +25°C $\pm 5^\circ\text{C}$   
Voltage charge time: 1 min  
Voltage charge: 50 Vdc for  $V_R < 100 \text{ Vdc}$   
100 Vdc for  $V_R \geq 100 \text{ Vdc}$

**Performance**

**For  $V_R \leq 100 \text{ Vdc}$**   
 $\geq 3750 \text{ M}\Omega$  for  $C \leq 0.33\mu\text{F}$  (5000  $\text{M}\Omega$ )\*  
 $\geq 1250 \text{ s}$  for  $C > 0.33\mu\text{F}$  (5000 s)\*

**For  $V_R > 100 \text{ Vdc}$**   
 $\geq 30000 \text{ M}\Omega$  (50000  $\text{M}\Omega$ )\*

\*Typical value

**Test voltage between terminals:**

$1.6 \times V_R$  applied for 2 s at +25°C  $\pm 5^\circ\text{C}$

**TEST METHOD AND PERFORMANCE**

**Damp heat, steady state:**

**Test conditions**

Temperature: +40°C  $\pm 2^\circ\text{C}$   
Relative humidity (RH): 93%  $\pm 2\%$   
Test duration: 56 days

**Performance**

Capacitance change  $|\Delta C/C|$ :  $\leq 5\%$   
DF change ( $\Delta \text{tg}\delta$ ):  $\leq 50 \times 10^{-4}$  at 1kHz  
Insulation resistance:  $\geq 50\%$  of initial limit.

**Endurance:**

**Test conditions**

Temperature: +105°C  $\pm 2^\circ\text{C}$   
Test duration: 2000 h  
Voltage applied:  $1.25 \times V_C$

**Performance**

Capacitance change  $|\Delta C/C|$ :  $\leq 5\%$   
DF change ( $\Delta \text{tg}\delta$ ):  $\leq 50 \times 10^{-4}$  at 10kHz  
Insulation resistance:  $\geq 50\%$  of initial limit.

**Resistance to soldering heat:**

**Test conditions**

Solder bath temperature: +260°C  $\pm 5^\circ\text{C}$   
Dipping time (with heat screen): 10 s  $\pm 1 \text{ s}$

**Performance**

Capacitance change  $|\Delta C/C|$ :  $\leq 2\%$   
DF change ( $\Delta \text{tg}$ ):  $\leq 50 \times 10^{-4}$  at 10kHz  
Insulation resistance:  $\geq$  initial limit.

**Long term stability** (after two years):

**Storage**

standard environmental conditions (see page 12).

**Performance**

Capacitance change  $|\Delta C/C|$ :  $\leq 3\%$  for  $C \leq 0.1\mu\text{F}$   
 $\leq 2\%$  for  $C > 0.1\mu\text{F}$

**RELIABILITY**

Reference MIL HDB 217

**Application conditions:**

Temperature: +40°C  $\pm 2^\circ\text{C}$   
Voltage:  $0.5 \times V_R$   
Failure rate:  $\leq 2 \text{ FIT}$   
(1 FIT = 1  $10^{-9}$  failures/components h)

**Failure criteria:**

(according to DIN 44122)

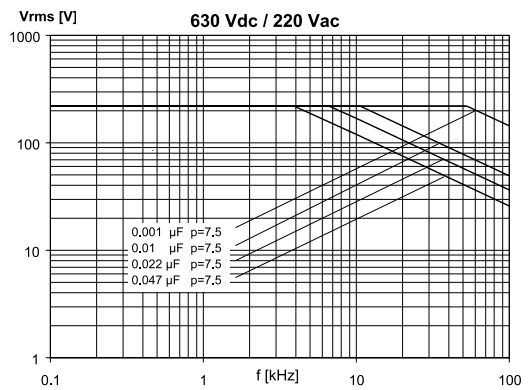
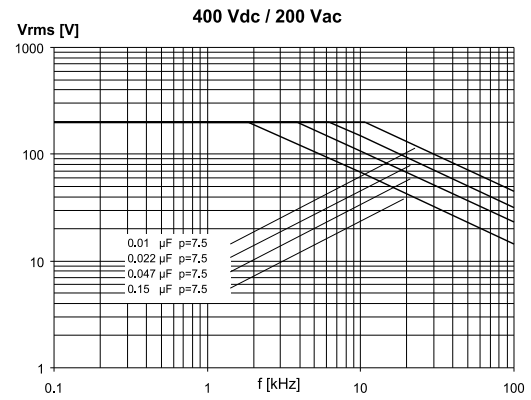
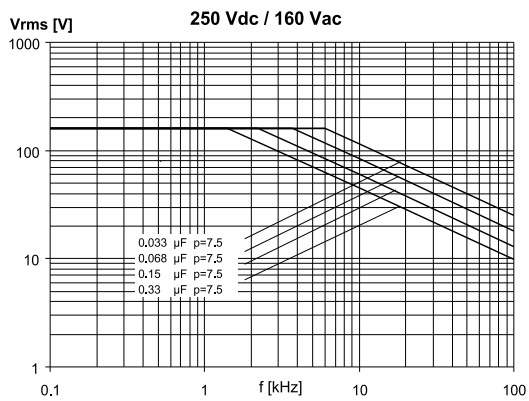
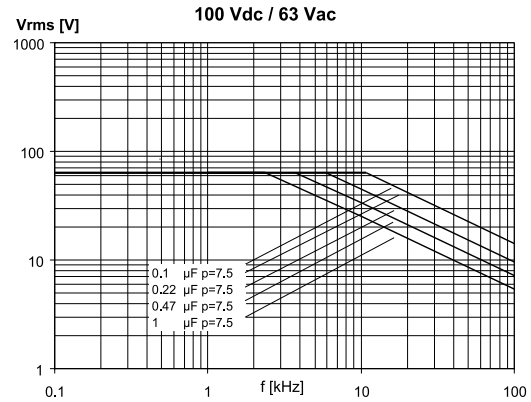
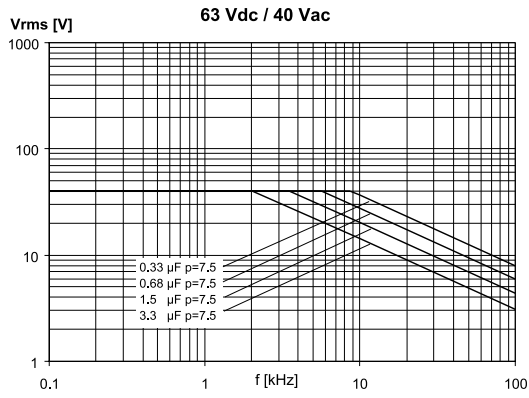
Short or open circuit  
Capacitance change  $|\Delta C/C|$ :  $> 10\%$   
DF change ( $\Delta \text{tg}\delta$ ):  $> 2 \times$  initial limit.  
Insulation resistance:  $< 0.005 \times$  initial limit.

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D.C. MULTIPURPOSE APPLICATIONS

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MAX. VOLTAGE (Vr.m.s.) VERSUS FREQUENCY (sinusoidal wave-form / Th ≤ 40°C)



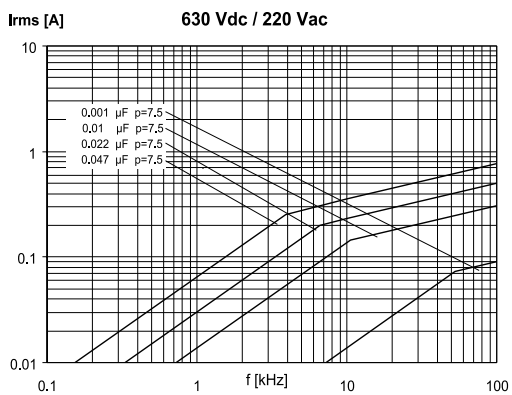
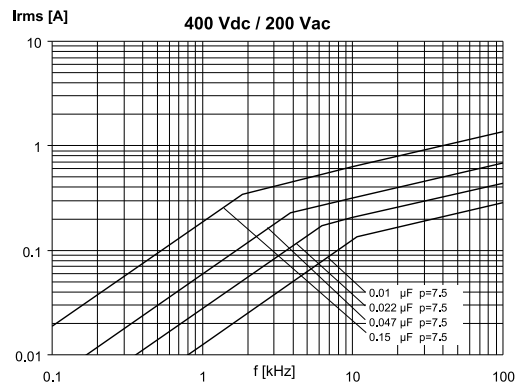
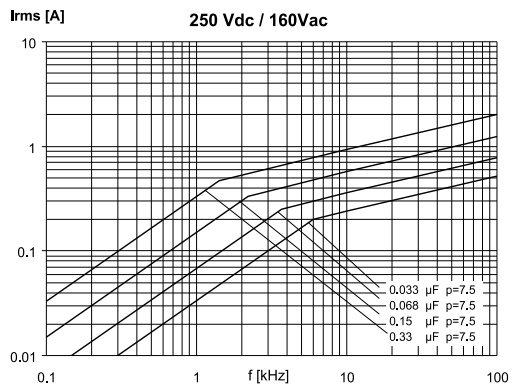
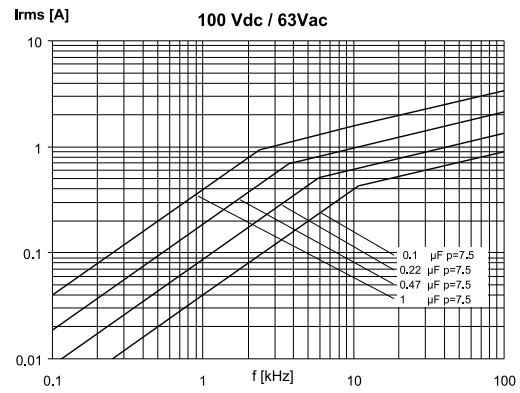
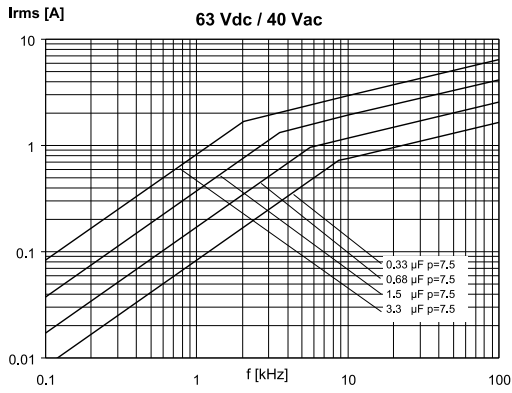
Note: p (pitch) in mm.

**METALLIZED POLYESTER FILM CAPACITOR  
D.C. MULTIPURPOSE APPLICATIONS**

$p = 7.5 \text{ mm}$

PRODUCT CODE: R66

MAX. CURRENT ( $I_{r.m.s.}$ ) VERSUS FREQUENCY (sinusoidal wave-form /  $T_h \leq 40^\circ\text{C}$ )



Note:  $p$  (pitch) in mm.